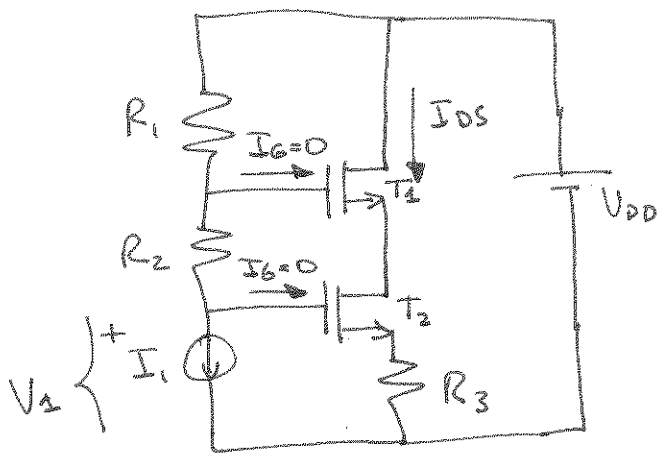


Solución ejercicio Refuerzo MOS:

a) Circuito en DC:



$$V_1 = V_{DD} - I_1 (R_1 + R_2) = 8.2 \text{ V}$$

MALLA G-S T2

$$V_1 = V_{GS2} + I_{DS} R_3$$

sup. T2 SATURACION

$$I_{DS} = \frac{K}{2} \frac{W}{L} (V_{GS2} - V_T)^2$$

$$\Rightarrow V_1 = V_{GS2} + \frac{K}{2} \frac{W}{L} R_3 (V_{GS2} - V_T)^2 \Rightarrow 8.2 = V_{GS2} + 0.2 (V_{GS2} - 1)^2 \Rightarrow$$

$$\Rightarrow 0.2 V_{GS2}^2 + 0.6 V_{GS2} - 8 = 0 \quad \left\{ \begin{array}{l} 5 \text{ V} \\ -8 \text{ V} \end{array} \right. \quad \text{como } V_{GS} > V_T \Rightarrow \underline{V_{GS} = 5 \text{ V}}$$

$$\Rightarrow I_{DS} = 3.2 \text{ mA}$$

SUP. SATURACION T1

$$I_{DS} = \frac{K}{2} \frac{W}{L} (V_{GS1} - V_T)^2 \Rightarrow V_{GS1} = 3.83 \text{ V}$$

Calculamos V_{DS1} y V_{DS2} para comprobar las suposiciones:

$$V_{DS1} = I_1 \cdot R_1 + V_{GS1} = 5.03 \text{ V} \quad V_{DS1} > V_{GS1} - V_T \quad \checkmark$$

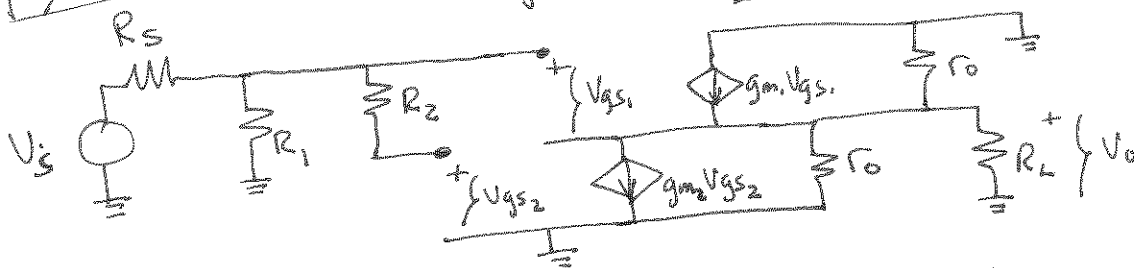
$$V_{DS2} = V_{DD} - I_1 R_2 - V_{GS1} - I_{DS} R_3 = 6.77 \text{ V} \quad V_{DS2} > V_{GS2} - V_T \quad \checkmark$$

$$g_{m1} = \sqrt{2K \frac{W}{L} I_{DS}} = 2.26 \text{ mA/V}$$

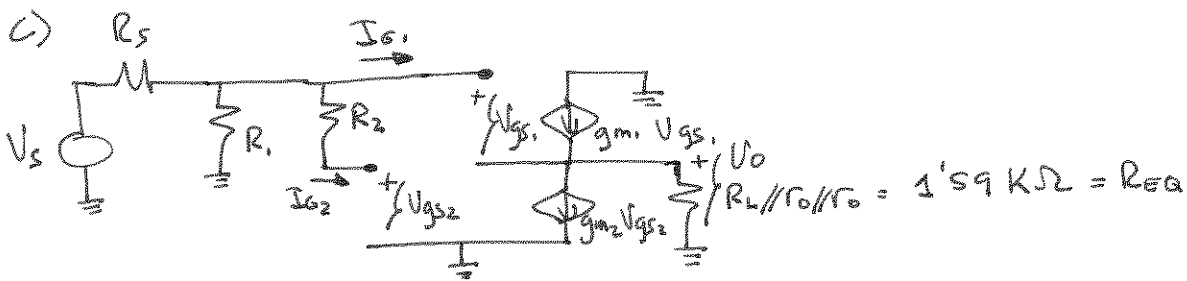
$$g_{m2} = \sqrt{2K \frac{W}{L} I_{DS}} = 1.6 \text{ mA/V}$$

$$r_{o1} = r_{o2} = r_o = \frac{V_A}{I_{DS}} = 15.6 \text{ k}\Omega$$

b) pequeña señal



NOTA: R_L y las dos r_o están en paralelo \Rightarrow



$$\begin{aligned} I_{G2} = 0 &\Rightarrow I_{G2} R_2 = 0 \Rightarrow V_{gs2} = U_s \frac{R_1}{R_s + R_1} \\ I_{G1} = 0 &\Rightarrow V_{gs1} = V_{gs2} - V_o \end{aligned}$$

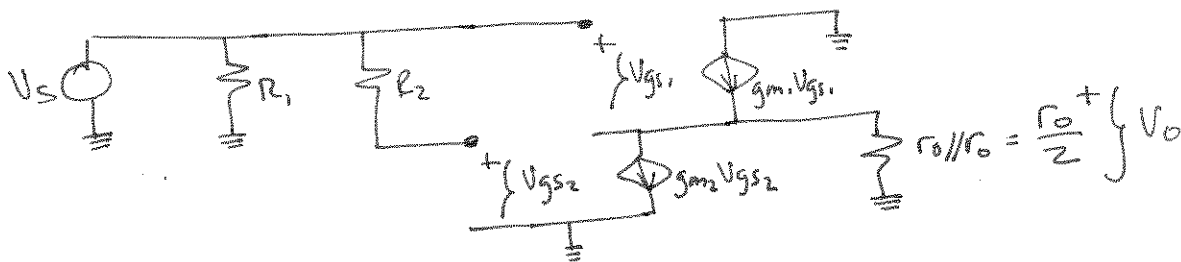
Leq Kirchhoff $\Rightarrow g_{m1} V_{gs1} = g_{m2} V_{gs2} + \frac{V_o}{R_{EQ}} \Rightarrow$

$$\Rightarrow g_{m1} \left(U_s \frac{R_1}{R_s + R_1} - V_o \right) = g_{m2} U_s \frac{R_1}{R_s + R_1} + \frac{V_o}{R_{EQ}}$$

$$\Rightarrow (g_{m1} - g_{m2}) \frac{R_1}{R_s + R_1} U_s = \left(g_{m1} + \frac{1}{R_{EQ}} \right) V_o$$

$$\Rightarrow \frac{V_o}{U_s} = \frac{(g_{m1} - g_{m2}) \frac{R_1}{R_s + R_1}}{g_{m1} + \frac{1}{R_{EQ}}} = 0.125$$

d) Si $R_s = 0$, $R_L = \infty$

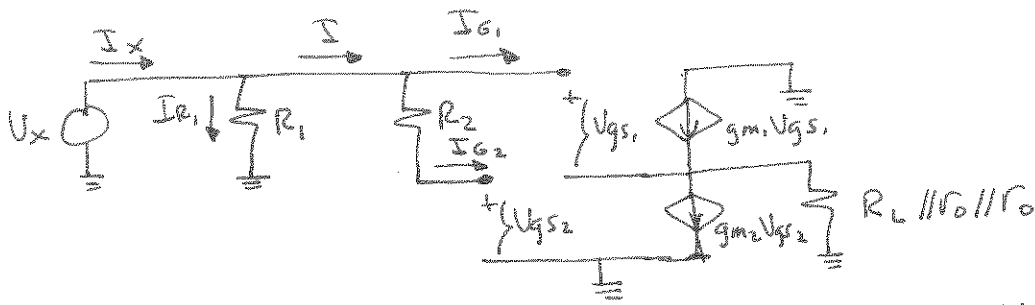


$$V_{gs2} = U_s \quad V_{gs1} = U_s - V_o \quad g_{m1} V_{gs1} = g_{m2} V_{gs2} + \frac{V_o}{r_o/2}$$

$$\Rightarrow g_{m1} (U_s - V_o) = g_{m2} U_s + \frac{2V_o}{r_o} \Rightarrow (g_{m1} - g_{m2}) U_s = \left(g_{m1} + \frac{2}{r_o} \right) V_o$$

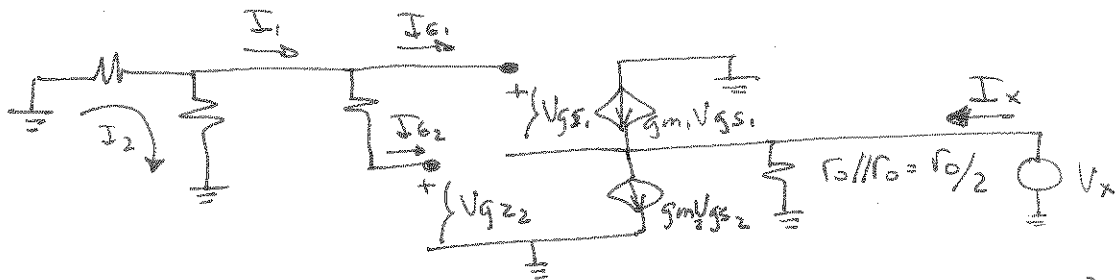
$$\Rightarrow \frac{V_o}{U_s} = \frac{g_{m1} - g_{m2}}{g_{m1} + \frac{2}{r_o}} = 0.276$$

e) R_{IN} :



$$I_{G1} = I_{G2} = 0 \Rightarrow I = 0 \Rightarrow I_{R1} = I_x \Rightarrow R_{IN} = \frac{V_x}{I_x} = R_1 = 600\Omega$$

R_{OUT} :



$$I_{G1} = I_{G2} = 0 \Rightarrow I_1 = 0 \quad \text{Malla} \rightarrow I_2 = 0 \Rightarrow V_{GS2} = 0 \Rightarrow g_{m2} V_{GS2} = 0$$

$$V_{GS1} = -V_x \Rightarrow I_x = \frac{V_x}{r_o/2} + g_{m1} V_x \Rightarrow R_{OUT} = \frac{V_x}{I_x} = \left(\frac{2}{r_o} + g_{m1} \right)^{-1} = 419\Omega$$

NOTA: se cumple que: $\frac{V_o}{V_s} = \frac{R_{IN}}{R_s + R_{IN}} \frac{V_o}{V_s} (R_s = 0, R_L = \infty) \frac{R_L}{R_{OUT} + R_L} \text{ (*)}$

resultados sin incluir efecto Early: ($r_o \rightarrow \infty$)

$$\frac{V_o}{V_s} = \frac{(g_{m1} - g_{m2}) \frac{R_1}{R_s + R_1}}{g_{m1} + \frac{1}{R_L}} = 0.130$$

$$\frac{V_o}{V_s} (R_s = 0, R_L = \infty) = \frac{g_{m1} - g_{m2}}{g_{m1}} = 0.292$$

tambien cumplen (*)

$$R_{IN} = R_1 = 600\Omega$$

$$R_{OUT} = \frac{1}{g_{m1}} = 442\Omega$$

1) para poder aplicar pequeña señal \Rightarrow
 \Rightarrow ambos transistores en saturación

$$T_1: V_{DS1} = I_1 R_1 + V_{GS1} \Rightarrow V_{DS1} > V_{GS1} - V_T \text{ siempre se cumple}$$

$$T_2: V_{DS2} = \frac{V_{DD}}{n} - \frac{I_1 R_1}{n} - V_{GS1} - \frac{I_{DS} R_3}{n}$$

No dependen de $\frac{w}{L}_1$ (I_{DS} es solución de la malla G-S para T_2)

$$I_{DS} = \frac{K}{2} \frac{w}{L}_1 (V_{GS1} - V_T)^2 \Rightarrow \text{Si } \frac{w}{L}_1 \downarrow \Rightarrow V_{GS1} \uparrow \Rightarrow V_{DS2} \downarrow$$

$$\text{límite con triodo} \Rightarrow V_{DS2} = V_{GS2} - V_T = 4V \Rightarrow V_{GS1} = 6.6V$$

$$\Rightarrow \frac{w}{L}_1 = \frac{2I_{DS}}{K} \frac{1}{(V_{GS1} - V_T)^2} = 10^2$$